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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







# **MA2S101**

## Silicon epitaxial planar type

#### For switching circuits

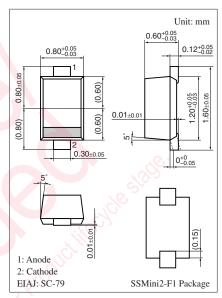
#### ■ Features

- High breakdown voltage:  $V_R = 250 \text{ V}$
- Small terminal capacitance C<sub>t</sub>
- Suitable for high-density mounting

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Reverse voltage	$V_R$	250	V
Repetitive peak reverse voltage	V <sub>RRM</sub>	250	V
Forward current	$I_{\mathrm{F}}$	100	mA
Peak forward current	$I_{FM}$	225	mA
Non-repetitive peak forward	$I_{FSM}$	500	mA
surge current *			
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Note) \*: t = 1 s



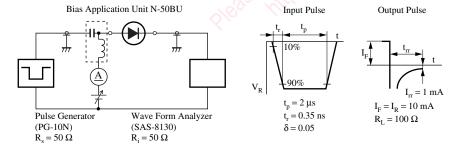
Marking Symbol: 1P

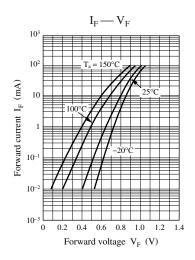
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

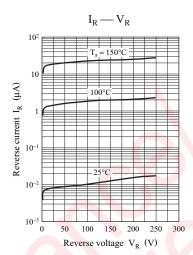
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	$I_F = 70 \text{ mA}$		950	1.2	V
Reverse current	$I_R$	$V_R = 250 \text{ V}$	00/		1.0	μΑ
Terminal capacitance	$C_{t}$	$V_R = 0 V, f = 1 MHz$	0.7		3.0	pF
Reverse recovery time *	t <sub>rr</sub>	$I_F = I_R = 10 \text{ mA}$			60	ns
		$I_{rr} = 1 \text{ mA}$ , $R_L = 100 \Omega$				

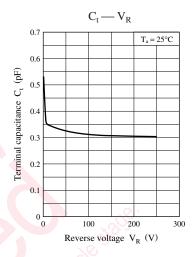
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

- 2. Absolute frequency of input and output is 20 MHz.
- 3. \*: t<sub>rr</sub> measurement circuit









2 SKF00062BED

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